TOSHIBA CMOS Didital Integrated Circuit Silicon Monolithic

TC7MET138AFK

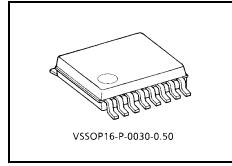
3-to-8 Line Decoder

The TC7MET138AFK is an advanced high speed CMOS 3-to-8 line decoder fabricated with silicon gate $\mathrm{C}^2\mathrm{MOS}$ technology. It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 binary select inputs (A, B and C) determine which one of the outputs $(\overline{Y}0 \cdot \overline{Y}7)$ will go low.

When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high. G1, $\overline{G}2A$, and $\overline{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

The input voltage are compatible with TTL output voltage. This device may be used as a level converter for interfacing $3.3\ V$ to $5\ V$ system.



Weight: 0.02 g (typ.)

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output ^(Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: $V_{CC} = 0 V$

Features

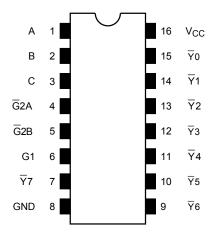
- High speed: $t_{pd} = 7.6 \text{ ns (typ.) (VCC} = 5 \text{ V)}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- Compatible with TTL outputs: V_{IL} = 0.8 V (max)

 $V_{IH} = 2.0 \text{ V (min)}$

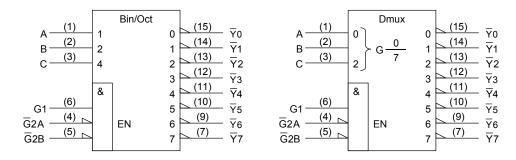
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with the 74 series (74AC/HC/ALS/LS etc.) 138 type.

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Pin Assignment (top view)



IEC Logic Symbol

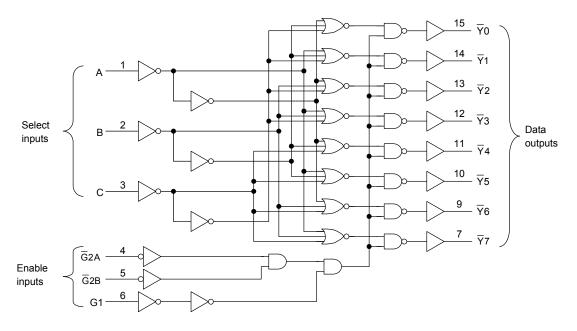


Truth Table

	Inputs					Outputs										
	Enable		Select		₹0	<u>7</u> 1	√ Y2	_ Y3	<u></u>	_ Y5	<u></u>	7 7	Selected Output			
G1	G ₂ A	G ₂ B	С	В	Α	10	T I	12	13	14	15	10	17			
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None		
Х	Н	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None		
Х	Х	Н	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None		
Н	L	L	Ш	L	L	L	Η	Н	Н	Н	Н	Н	Ι	₹0		
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	₹1		
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	Ÿ2		
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	Y 3		
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	₹4		
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Ȳ5		
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	₹6		
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	₹7		

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5~7.0	٧	
DC input voltage	V _{IN}	-0.5~7.0	V	
DC output voltage	Vout	−0.5~7.0 (Note 2)	V	
De output voltage	VOU1	-0.5~V _{CC} + 0.5 (Note 3)	V	
Input diode current	lıK	-20	mA	
Output diode current	lok	±20 (Note 4)	mA	
DC output current	lout	±25	mA	
DC V _{CC} /ground current	Icc	±75	mA	
Power dissipation	PD	180	mW	
Storage temperature	T _{stg}	-65~150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$



Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	4.5~5.5	V	
Input voltage	V _{IN}	0~5.5	٧	
Output voltage	Vour	0~5.5 (Note 2)	V	
Output voltage	V _{OUT}	0~V _{CC} (Note 3)	V	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~20	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: $V_{CC} = 0 V$

Note 3: High or low state.

Electrical Characteristics

DC Characteristics

Charact	Symbol	Test Condition			-	Га = 25°C		Ta = -4	Unit		
Characteristics		Syllibol	rest Condition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Input voltage	High level	V _{IH}	_		4.5~5.5	2.0	_	_	2.0	_	V
input voltage	Low level	V _{IL}		_	4.5~5.5		_	0.8	_	0.8	٧
	High level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \mu A$	4.5	4.4	4.5	_	4.4	_	· V
Output voltage	riigirievei	VOH		$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	_	3.80	_	
Output voitage	Low level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	$I_{OL} = 50 \ \mu A$	4.5	_	0	0.1	_	0.1	
				I _{OL} = 8 mA	4.5	_	_	0.36	_	0.44	
Input leakage current		I _{IN}	V _{IN} = 5.5 V or GND		0~5.5	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current		I _{CC}	$V_{IN} = V_{CC}$	or GND	5.5	_	_	4.0	_	40.0	μΑ
		Ісст	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5		_	1.35	_	1.50	mA
Output leakage	I _{OPD}	V _{OUT} = 5.	5 V	0		_	0.5	_	5.0	μΑ	

AC Characteristics (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -4	- Unit	
Characteristics	Syllibol	rest Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Offic
Propagation delay time	t _{pLH}	_	5.0 ± 0.5	15		7.6	10.4	1.0	12.0	- ns
$(A, B, C-\overline{Y})$	t _{pHL}			50	_	8.1	11.4	1.0	13.0	
Propagation delay time	t _{pLH}		5.0 ± 0.5	15		6.6	9.1	1.0	10.5	- ns
(G1- \overline{Y})	tpHL	_		50	_	7.1	10.1	1.0	11.5	
Propagation delay time	t _{pLH}		5.0 ± 0.5	15		7.0	9.6	1.0	11.0	- ns
(G 2 - Y)	tpHL			50		7.5	10.6	1.0	12.0	
Input capacitance	C _{IN}		_			4	10	_	10	pF
Power dissipation capacitance	C_{PD}			(Note)		49		_		pF

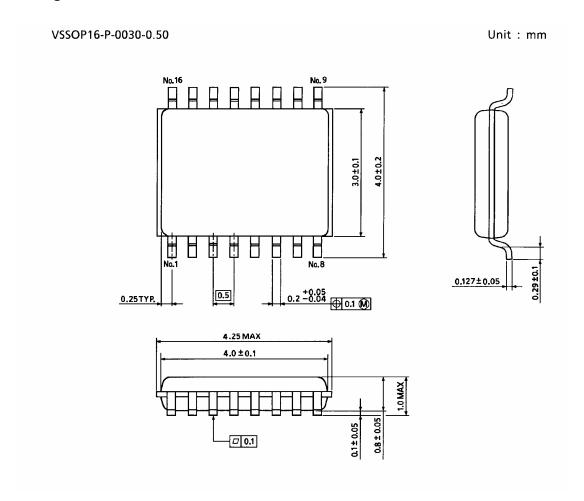
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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